# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



BPV11

**Vishay Semiconductors** 

## Silicon NPN Phototransistor

#### **FEATURES**

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- · High photo sensitivity
- High radiant sensitivity
- · Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 15^{\circ}$
- · Base terminal connected
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

• Detector for industrial electronic circuitry, measurement and control

#### **PRODUCT SUMMARY** COMPONENT Ica (mA) φ (deg) λ<sub>0.1</sub> (nm) BPV11 450 to 1080 10 ± 15

#### Note

DESCRIPTION

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
BPV11	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾				

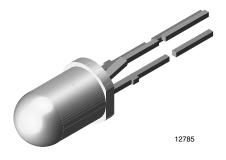
#### Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Collector base voltage		V <sub>CBO</sub>	80	V				
Collector emitter voltage		V <sub>CEO</sub>	70	V				
Emitter base voltage		V <sub>EBO</sub>	5	V				
Collector current		Ι <sub>C</sub>	50	mA				
Collector peak current	$t_p/T$ = 0.5, $t_p \le 10$ ms	I <sub>CM</sub>	100	mA				
Power dissipation	$T_{amb} \le 47 \ ^{\circ}C$	Pv	150	mW				
Junction temperature		Тj	100	°C				
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C				
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C				
Soldering temperature	$t \leq 5 \; \text{s}, 2 \; \text{mm}$ from body	T <sub>sd</sub>	260	°C				
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	350	K/W				

Document Number: 81504





BPV11 is a silicon NPN phototransistor with high radiant

sensitivity in clear, T-1¾ plastic package with base terminal.

It is sensitive to visible and near infrared radiation.



RoHS

COMPLIANT

HALOGEN FREE

<u>GREEN</u>

(5-2008)







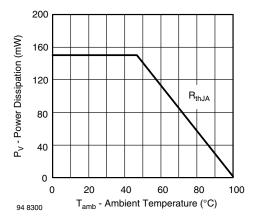


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V		
Collector emitter dark current	V <sub>CE</sub> = 10 V, E = 0	I <sub>CEO</sub>		1	50	nA		
DC current gain	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ E} = 0$	h <sub>FE</sub>		450				
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C <sub>CEO</sub>		15		pF		
Collector base capacitance	$V_{BE} = 0 V, f = 1 MHz, E = 0$	C <sub>CBO</sub>		19		pF		
Collector light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_{CE} = 5 \text{ V}$	I <sub>ca</sub>	3	10		mA		
Angle of half sensitivity		φ		± 15		deg		
Wavelength of peak sensitivity		λρ		850		nm		
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1080		nm		
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 1 \text{ mA}$	V <sub>CEsat</sub>		130	300	mV		
Turn-on time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>on</sub>		6		μs		
Turn-off time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>off</sub>		5		μs		
Cut-off frequency	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	f <sub>c</sub>		110		kHz		

#### BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

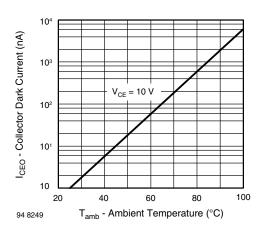


Fig. 2 - Collector Dark Current vs. Ambient Temperature

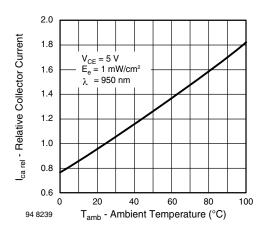


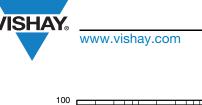
Fig. 3 - Relative Collector Current vs. Ambient Temperature

Rev. 1.8, 03-May-13

2 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

### **Vishay Semiconductors**



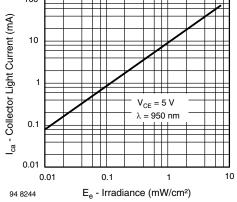


Fig. 4 - Collector Light Current vs. Irradiance

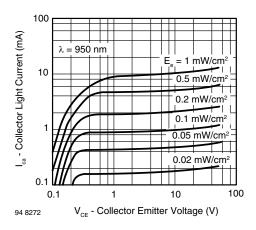


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

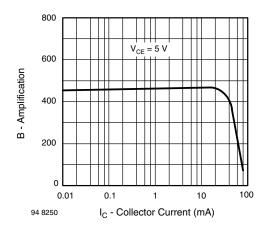


Fig. 6 - Amplification vs. Collector Current

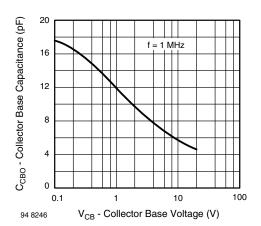


Fig. 7 - Collector Base Capacitance vs. Collector Base Voltage

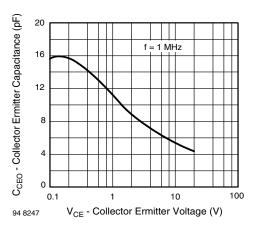


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

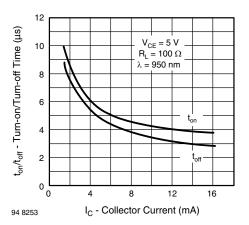
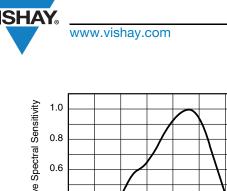


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

3 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

## **Vishay Semiconductors**



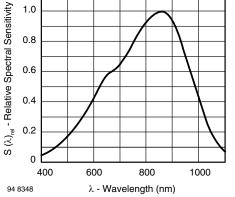
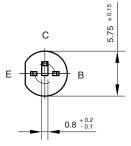


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

#### **PACKAGE DIMENSIONS** in millimeters



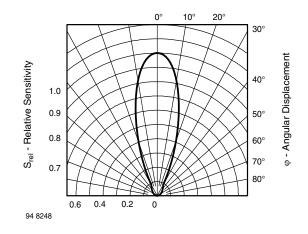
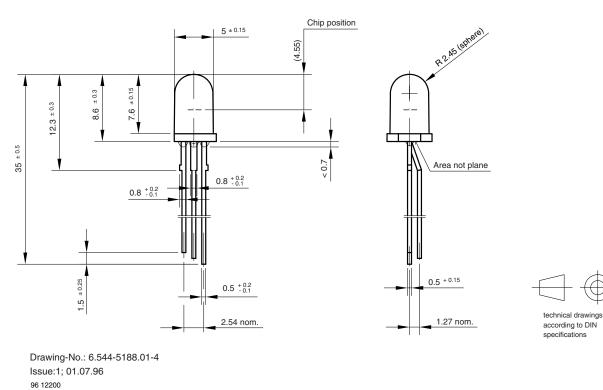


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement



4 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.